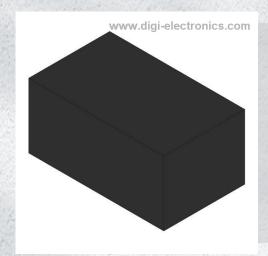


# **NX7002BKMBYL Datasheet**



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DiGi Electronics Part Number NX7002BKMBYL-DG

Manufacturer NXP Semiconductors

Manufacturer Product Number NX7002BKMBYL

Description NEXPERIA NX7002B - 60V, N-CHANNE

Detailed Description N-Channel 60 V 350mA (Ta) 350mW (Ta), 3.1W (Tc)

Surface Mount DFN1006B-3



Tel: +00 852-30501935

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## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
NX7002BKMBYL	NXP Semiconductors
Series:	Product Status:
TrenchMOS™	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
60 V	350mA (Ta)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
5V, 10V	2.80hm @ 200mA, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
2.1V @ 250µA	1 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	23.6 pF @ 10 V
FET Feature:	Power Dissipation (Max):
	350mW (Ta), 3.1W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
DFN1006B-3	3-XFDFN

## **Environmental & Export classification**

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected



## NX7002BKMB

## 60 V, N-channel Trench MOSFET

3 December 2014

**Product data sheet** 

### 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

#### 2. Features and benefits

- Logic-level compatible
- Very fast switching
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2kV HBM

## 3. Applications

- · Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

#### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	60	V
$V_{GS}$	gate-source voltage			-20	-	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C	[1]	-	-	350	mA
Static characte	Static characteristics				,		
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 200 \text{ mA}; T_j = 25 \text{ °C}$		-	2.2	2.8	Ω

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.



## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	1 🔲	D I
2	S	source	3	
3	D	drain	Transparent top view  DFN1006B-3 (SOT883B)	G S 017aaa255

## 6. Ordering information

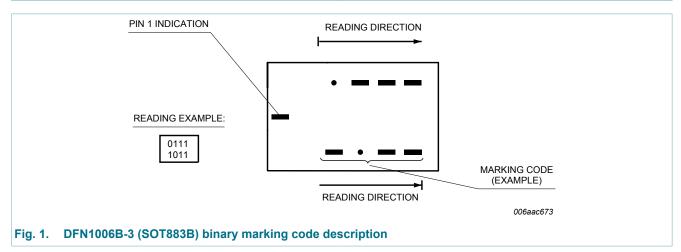
Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
NX7002BKMB	DFN1006B-3	DFN1006B-3: leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.37 mm	SOT883B		

## 7. Marking

Table 4. Marking codes

Type number	Marking code
NX7002BKMB	0101 0111



## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	60	V
$V_{GS}$	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C	[1]	-	350	mA
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 100 °C	[1]	-	200	mA
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10$ μs		-	0.9	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	350	mW
			[1]	-	680	mW
		T <sub>sp</sub> = 25 °C		-	3100	mW
T <sub>j</sub>	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drain o	liode					_
Is	source current	T <sub>amb</sub> = 25 °C	[1]	-	200	mA

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

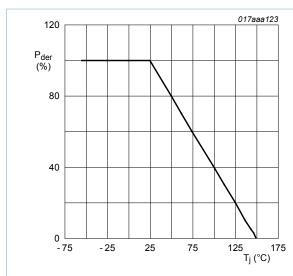


Fig. 2. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

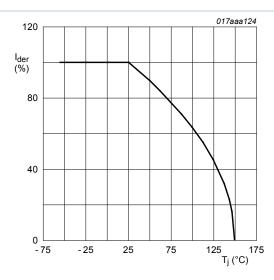


Fig. 3. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100 \%$$

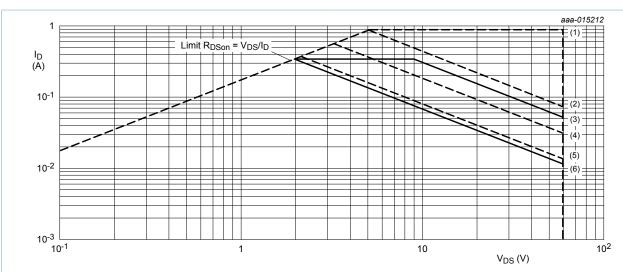
NX7002BKMB

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NX7002BKMB

60 V, N-channel Trench MOSFET



I<sub>DM</sub> = single pulse

(1) 
$$t_p = 10 \ \mu s$$

(2) 
$$t_p = 1 \text{ ms}$$

(3) DC; 
$$T_{sp} = 25 \,^{\circ}\text{C}$$

$$(4) t_p = 10 ms$$

$$(5) t_p = 100 \text{ ms}$$

(6) DC;  $T_{amb}$  = 25 °C; drain mounting pad 1 cm<sup>2</sup>

Fig. 4. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drainsource voltage

#### 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
from ju	thermal resistance		[1]	-	314	360	K/W
	from junction to ambient		[2]	-	159	180	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	35	40	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.

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60 V, N-channel Trench MOSFET

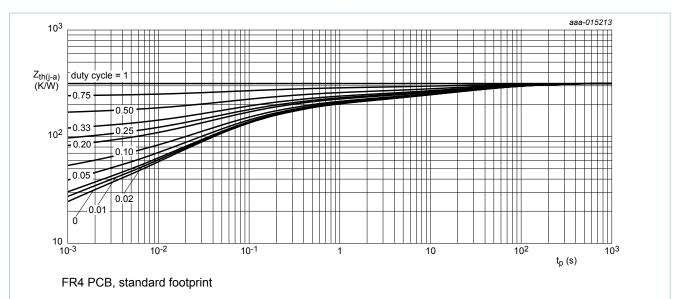


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

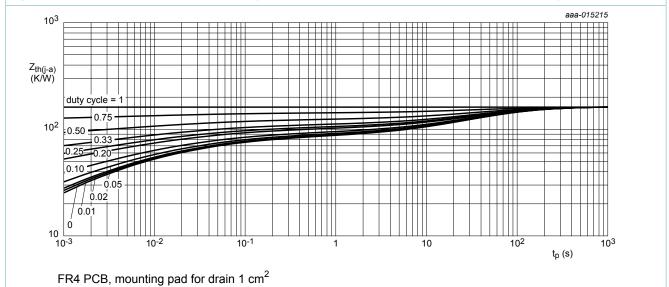


Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## NX7002BKMB

**60 V, N-channel Trench MOSFET** 

## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	60	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = 250 \ \mu A; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^{\circ}C$	1.1	1.6	2.1	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	1	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-10	μA
		V <sub>GS</sub> = 10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	1	μA
		V <sub>GS</sub> = -10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-1	μA
		V <sub>GS</sub> = 5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	0.3	μA
		V <sub>GS</sub> = -5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-0.3	μA
R <sub>DSon</sub> drain-source on-staresistance	drain-source on-state	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 200 mA; T <sub>j</sub> = 25 °C	-	2.2	2.8	Ω
	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 100 mA; T <sub>j</sub> = 150 °C	-	4.5	5.7	Ω
		V <sub>GS</sub> = 5 V; I <sub>D</sub> = 200 mA; T <sub>j</sub> = 25 °C	-	2.5	3.2	Ω
9 <sub>fs</sub>	forward transconductance	$V_{DS}$ = 10 V; $I_{D}$ = 200 mA; $T_{j}$ = 25 °C	-	600	-	mS
$R_G$	internal gate resistance (AC)	f = 2.5 MHz	-	2.5	-	Ω
Dynamic ch	naracteristics		·			
Q <sub>G(tot)</sub>	total gate charge	V <sub>DS</sub> = 30 V; I <sub>D</sub> = 200 mA; V <sub>GS</sub> = 10 V;	-	1	-	nC
$Q_{GS}$	gate-source charge	T <sub>j</sub> = 25 °C	-	0.12	-	nC
$Q_{GD}$	gate-drain charge		-	0.18	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 10 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	23.6	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	4.6	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	3	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 50 V; $I_{D}$ = 200 mA; $V_{GS}$ = 10 V;	-	4.7	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega$ ; $T_j = 25 ^{\circ}C$	-	4.3	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	6.9	-	ns
t <sub>f</sub>	fall time		-	2.9	-	ns
Source-dra	in diode		I		-1	
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 200 mA; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	0.87	1.2	V

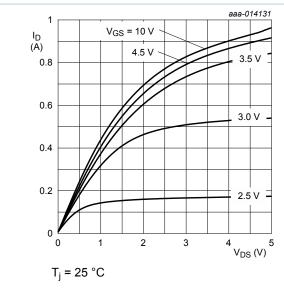
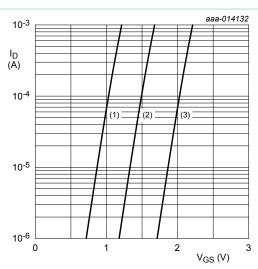


Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values



 $T_i = 25 \,^{\circ}C; \, V_{DS} = 5 \,^{\circ}V$ 

- (1) minimum values
- (2) typical values
- (3) maximum values

Fig. 8. Sub-threshold drain current as a function of gate-source voltage

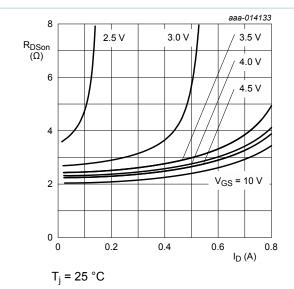
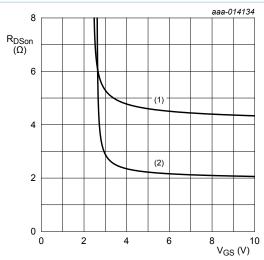


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values



 $I_D = 0.2 A$ 

(1)  $T_i = 150 \, ^{\circ}C$ 

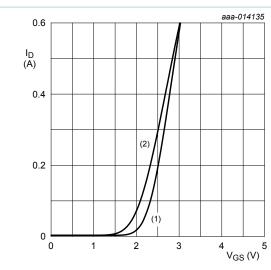
(2)  $T_i = 25 \, ^{\circ}C$ 

Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

2.5

aaa-014136

#### **60 V, N-channel Trench MOSFET**



 $V_{DS} > I_D \times R_{DSon}$ 

(1)  $T_j = 25$  °C

(2)  $T_j = 150 \, ^{\circ}C$ 

Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

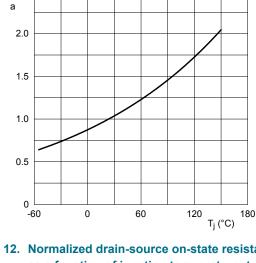
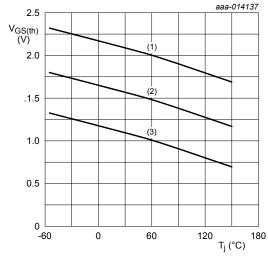


Fig. 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values

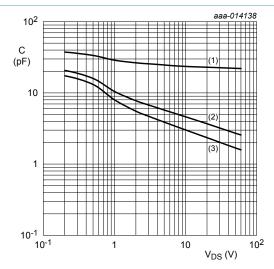
$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$



 $I_D = 0.25 \text{ mA}; V_{DS} = V_{GS}$ 

- (1) maximum values
- (2) typical values
- (3) minimum values

Fig. 13. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$ 

- (1) C<sub>iss</sub>
- (2) C<sub>oss</sub>
- $(3)\;C_{rss}$

Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

## NX7002BKMB

#### 60 V, N-channel Trench MOSFET

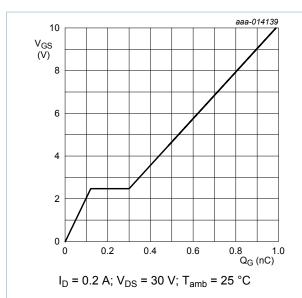


Fig. 15. Gate-source voltage as a function of gate charge; typical values

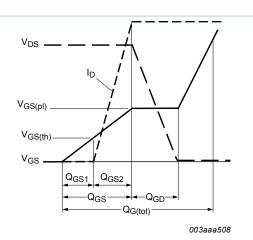
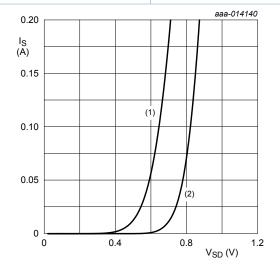


Fig. 16. MOSFET transistor: Gate charge waveform definitions



 $V_{GS} = 0 V$ (1)  $T_j = 150 \,^{\circ}C$ 

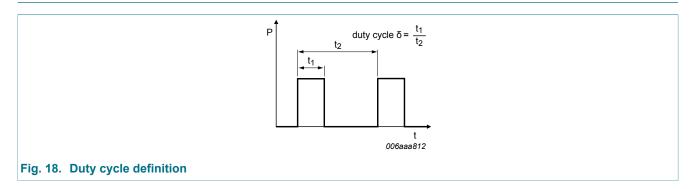
(2)  $T_i = 25 \, ^{\circ}C$ 

Fig. 17. Source current as a function of source-drain voltage; typical values

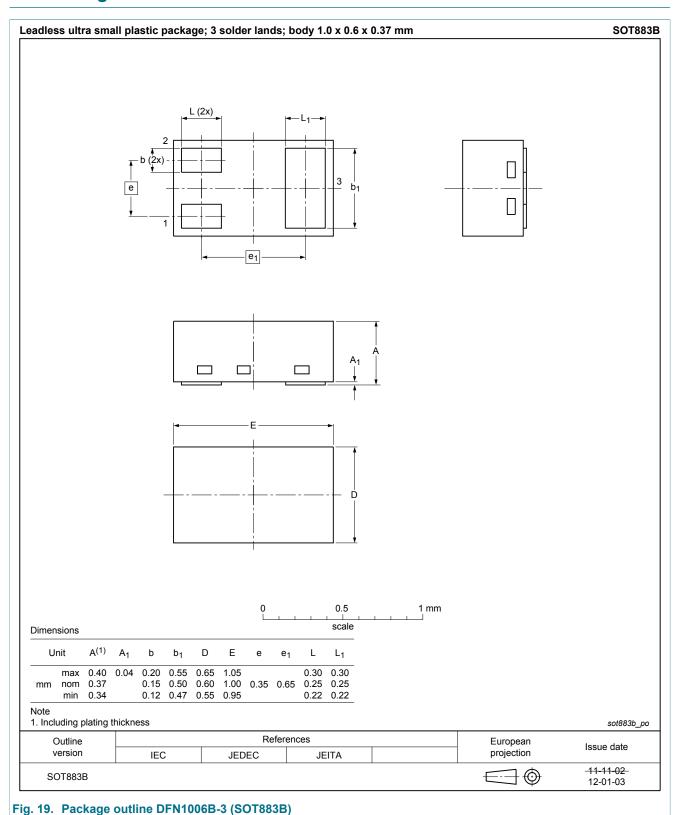
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**60 V, N-channel Trench MOSFET** 

## 11. Test information



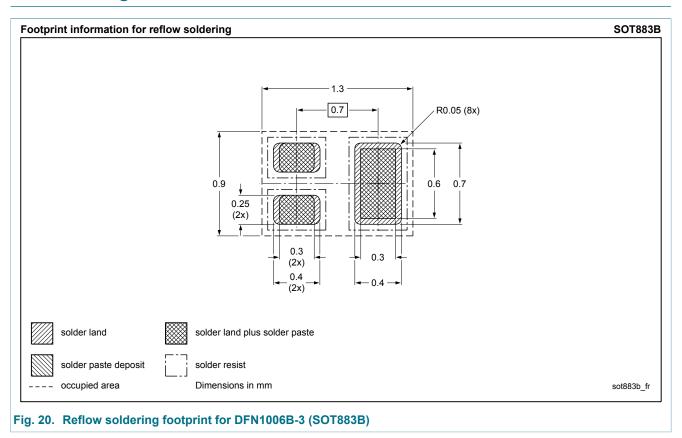
## 12. Package outline



NX7002BKMB

60 V, N-channel Trench MOSFET

## 13. Soldering



NX7002BKMB

**60 V, N-channel Trench MOSFET** 

## 14. Revision history

#### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
NX7002BKMB v.2	20141203	Product data sheet	-	NX7002BKMB v.1
Modification:	Figure 3 updated			
NX7002BKMB v.1	20141001	Product data sheet	-	-

Nexperia NX7002BKMB

#### 60 V, N-channel Trench MOSFET

### 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## NX7002BKMB

#### **60 V, N-channel Trench MOSFET**

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